

# BCR12LM-12LB

 Triac
 R07DS0068EJ0100

 Rev.1.00
 Rev.1.00

 Jul 27, 2010
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#### **Features**

I<sub>T (RMS)</sub>: 12 A
 V<sub>DRM</sub>: 600 V

•  $I_{FGTI}$ ,  $I_{RGTI}$ ,  $I_{RGT III}$ : 30 mA

• V<sub>iso</sub>: 1800V

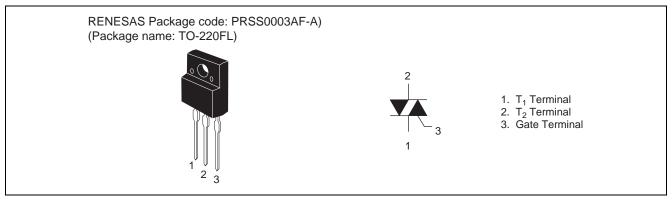
• The Product guaranteed maximum junction temperature 150°C

Insulated Type

• Planar Type

UL Recognized : File No. E223904

#### **Outline**



## **Applications**

Switching mode power supply, light dimmer, electronic switch, hair dryer, Television, Stereo system, refrigerator, Washing machine, infrared kotatsu, and carper, small motor controller, SS relay, solenoid driver, copying machine, electric tool, electric heater control, and other general purpose control applications

| Parameter  | Symbol    | Voltage class | Unit |
|--|-----------|---------------|------|
| Faranietei   | Symbol    | 12            |      |
| Repetitive peak off-state voltage <sup>Note1</sup> | $V_{DRM}$ | 600           | V    |
| Non-repetitive peak off-state voltage Note1        | $V_{DSM}$ | 720           | V    |

| Parameter                      | Symbol               | Ratings     | Unit             | Conditions   |
|--------------------------------|----------------------|-------------|------------------|--|
| RMS on-state current           | I <sub>T (RMS)</sub> | 12          | Α                | Commercial frequency, sine full wave                 |
|                                |                      |             |                  | 360°conduction, Tc = 92°C                            |
| Surge on-state current         | I <sub>TSM</sub>     | 120         | Α                | 60Hz sinewave 1 full cycle, peak value,              |
|                                |                      |             |                  | non-repetitive                                       |
| I <sup>2</sup> t for fusion    | l <sup>2</sup> t     | 60          | A <sup>2</sup> s | Value corresponding to 1 cycle of half               |
|                                |                      |             |                  | wave 60Hz, surge on-state current                    |
| Peak gate power dissipation    | P <sub>GM</sub>      | 5           | W                |  |
| Average gate power dissipation | P <sub>G (AV)</sub>  | 0.5         | W                |  |
| Peak gate voltage              | $V_{GM}$             | 10          | V                |  |
| Peak gate current              | I <sub>GM</sub>      | 2           | Α                |  |
| Junction Temperature           | Tj                   | -40 to +150 | °C               |  |
| Storage temperature            | Tstg                 | -40 to +150 | °C               |  |
| Mass                           | _                    | 1.5         | g                | Typical value  |
| Isolation voltage              | V <sub>iso</sub>     | 1800        | V                | Ta = 25°C, AC 1 minute,                              |
|                                |                      |             |                  | T <sub>1</sub> • T <sub>2</sub> • G terminal to case |

Notes: 1. Gate open.

#### **Electrical Characteristics**

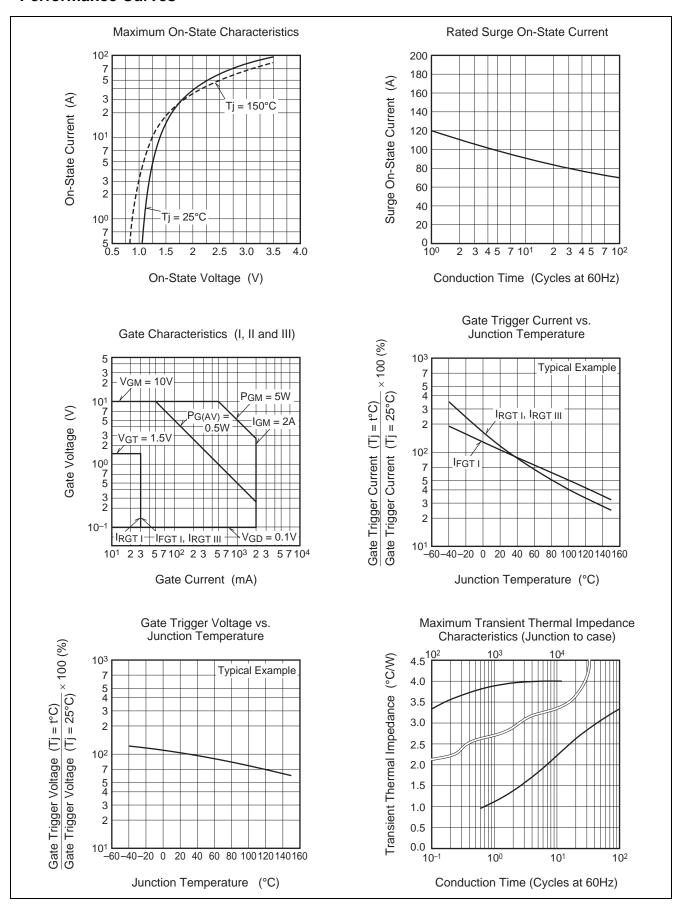
| Parameter  |     | Symbol                 | Min.    | Тур. | Max. | Unit | Test conditions  |  |
|--|-----|------------------------|---------|------|------|------|--|--|
| Repetitive peak off-state current                                      |     | I <sub>DRM</sub>       | _       | _    | 2.0  | mA   | Tj = 150°C, V <sub>DRM</sub> applied                         |  |
| On-state voltage   |     | $V_{TM}$               | _       | _    | 1.6  | V    | Tc = 25°C, I <sub>TM</sub> = 20 A, instantaneous measurement |  |
| Gate trigger voltage <sup>Note2</sup>                                  | I   | $V_{FGT_{\mathrm{I}}}$ | _       | _    | 1.5  | V    | $Tj = 25$ °C, $V_D = 6$ V, $R_L = 6$ Ω,                      |  |
|  | II  | $V_{RGT_{\mathrm{I}}}$ | _       | _    | 1.5  | V    | $R_G = 330 \Omega$   |  |
|  | III | $V_{RGT_{III}}$        | _       | _    | 1.5  | V    |  |  |
| Gate trigger curent <sup>Note2</sup>                                   | I   | I <sub>FGTI</sub>      | _       | _    | 30   | mA   | $Tj = 25$ °C, $V_D = 6$ V, $R_L = 6$ Ω,                      |  |
|  | II  | $I_{RGTI}$             | _       | _    | 30   | mA   | $R_G = 330 \Omega$   |  |
|  | III | I <sub>RGTIII</sub>    | _       | _    | 30   | mA   |  |  |
| Gate non-trigger voltage   |     | $V_{GD}$               | 0.2/0.1 | _    | _    | V    | $Tj = 125^{\circ}C/150^{\circ}C, V_D = 1/2 V_{DRM}$          |  |
| Thermal resistance   |     | R <sub>th (j-c)</sub>  | _       | _    | 4.0  | °C/W | Junction to case <sup>Note3</sup>                            |  |
| Critical-rate of rise of off-stat commutation voltage <sup>Note4</sup> | е   | (dv/dt)c               | 10/1    | _    | _    | V/μs | Tj = 125°C/150°C   |  |

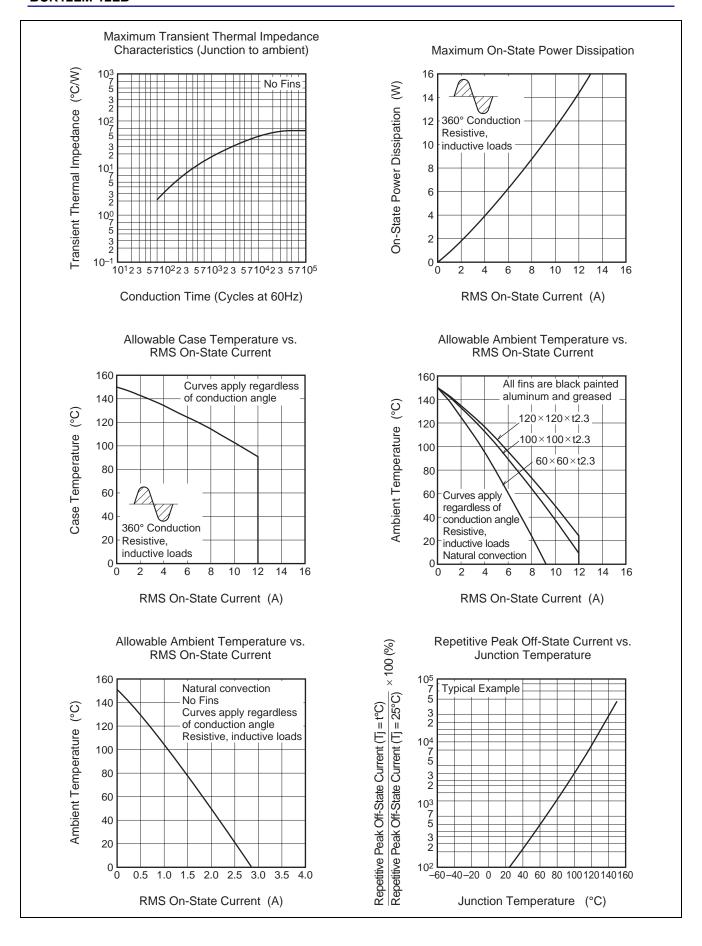
Notes: 2. Measurement using the gate trigger characteristics measurement circuit.

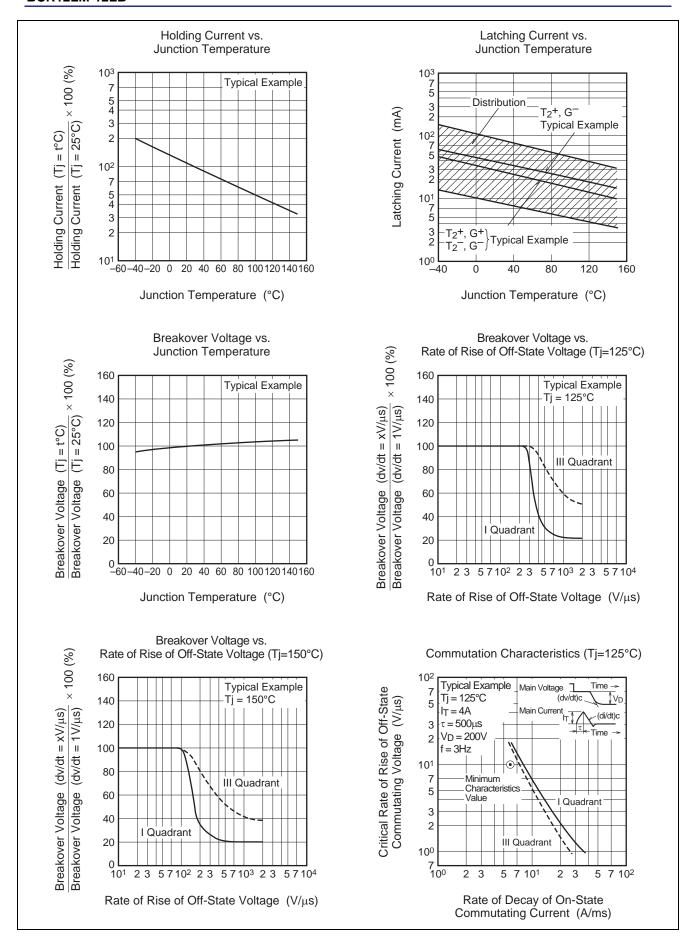
- 3. The contact thermal resistance  $R_{th\;(c\text{-}f)}$  in case of greasing is 0.5°C/W.
- 4. Test conditions of the critical-rate of rise of off-state commutation voltage is shown in the table below.

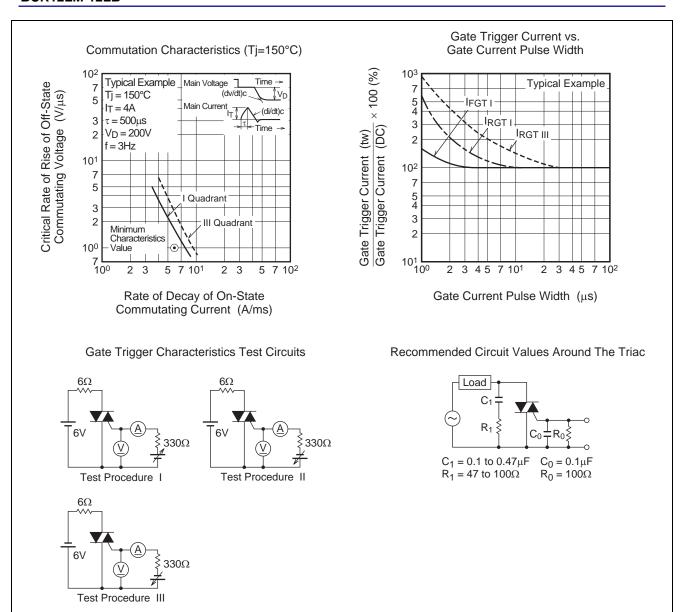
| Test conditions   | Commutating voltage and current waveforms |  |  |  |
|---|---|--|--|--|
|   | (inductive load)                          |  |  |  |
| 1. Junction temperature Tj = 125°C/150°C                              | Supply Voltage Time                       |  |  |  |
| 2. Rate of decay of on-state commutating current (di/dt)c = -6.0 A/ms | Main Current (di/dt)c                     |  |  |  |
| 3. Peak off-state voltage $V_D = 400 \text{ V}$                       | Main Voltage Time                         |  |  |  |

#### **Performance Curves**

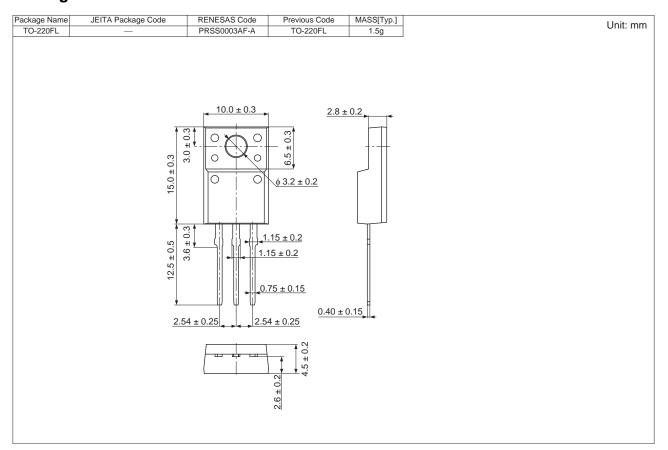








## **Package Dimensions**



### **Order Code**

| Lead form     | Standard packing        | Quantity | Standard order code           | Standard order code example |
|---------------|-------------------------|----------|-------------------------------|-----------------------------|
| Straight type | Plastic Magazine (Tube) | 50       | Type name                     | BCR12LM-12LB                |
| Lead form     | Plastic Magazine (Tube) | 50       | Type name – Lead forming code | BCR12LM-12LB-A8             |

Note: Please confirm the specification about the shipping in detail.

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